## <u>Standard specifications of</u> 100 mm β-Ga<sub>2</sub>O<sub>3</sub> epitaxial wafer (by HVPE)

## Epitaxial layer

Items	Specifications	
Dopant	Si (n-type)	$\beta$ -Ga <sub>2</sub> O <sub>3</sub> epitaxial layer
Doping concentration	1×10 <sup>16</sup> cm <sup>-3</sup>	$\beta$ -Ga <sub>2</sub> O <sub>3</sub> wafer
Thickness *A value can be selected in increments 1 µm.	Specify a value in the range between 5 and 10 µm	Cross section of β-Ga <sub>2</sub> O <sub>3</sub> epitaxial wafer
Wafer		
Items	Specifications	
Dopant	Sn (n-type)	IF (001)
Doping concentration	Using the range of $1 \times 10^{18} \sim 2 \times 10^{19}  \mathrm{cm}^{-3}$	
Orientation	(001)	
Size	100 mm	OF [100]
Thickness	0.65 mm	Orientation
XRD FWHM	≤350 arcsec	
Off set angle	0°±1°	
Remarks		

1 There are cases in which the other side of OF is chipped (a maximum of around IF width).

1 These products must be used for research and development purposes only.

2 The substrates must not be used as a seed crystal.

3 The specifications are subject to change without notice.

Novel Crystal Technology, Inc.

## <u>Standard specifications of</u> <u>2 inch β-Ga<sub>2</sub>O<sub>3</sub> epitaxial wafer (by HVPE)</u>

## Epitaxial layer

Items	Specifications	
Dopant	Si (n-type)	$\beta$ -Ga <sub>2</sub> O <sub>3</sub> epitaxial layer
Doping concentration *A value can be selected in increments of $1 \times 10^{16}$ cm <sup>-3</sup> .	Specify a value in the range between $1 \times 10^{16}$ and $9 \times 10^{16}$ cm <sup>-3</sup>	β-Ga <sub>2</sub> O <sub>3</sub> wafer Cross section of β-Ga <sub>2</sub> O <sub>3</sub>
Thickness *A value can be selected in increments 1 µm.	Specify a value in the range between 5 and 10 µm	epitaxial wafer
Wafer		
Items	Specifications	
Dopant	Sn (n-type)	IF (001)
Doping concentration	Using the range of $1 \times 10^{18} \sim 2 \times 10^{19}  \mathrm{cm}^{-3}$	
Orientation	(001)	
Size	2 inch	OF [100]
Thickness	0.65 mm	Orientation
XRD FWHM	≤350 arcsec	
Off set angle	0°±1°	
Remarks		

1 There are cases in which the other side of OF is chipped (a maximum of around IF width).

1 These products must be used for research and development purposes only.

2 The substrates must not be used as a seed crystal.

3 The specifications are subject to change without notice.

